

Silicon PNP Power Transistor

DESCRIPTION

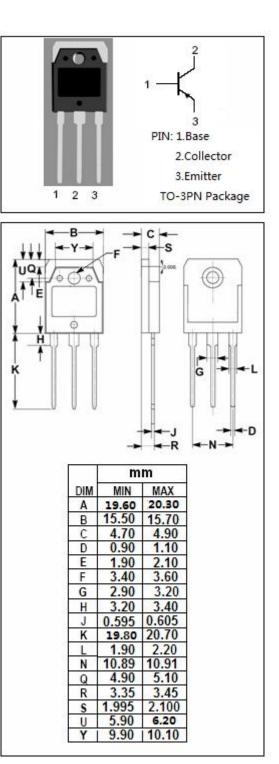
- High Collector-Emitter Breakdown Voltage-V_{(BR)CEO}= -180V(Min)
- Good Linearity of h_{FE}
- Complement to Type 2SC3856

APPLICATIONS

• For audio and general purpose applications

| ABSOLUTE MAXIMUM RATINGS(Ta=25°C) | | | | |
|-----------------------------------|---|---------|------|--|
| SYMBOL | PARAMETER | VALUE | UNIT | |
| V _{CBO} | Collector-Base Voltage -180 | | V | |
| V _{CEO} | Collector-Emitter Voltage | -180 | V | |
| V _{EBO} | Emitter-Base Voltage | -6 | V | |
| lc | Collector Current-Continuous -15 | | A | |
| lв | Base Current-Continuous -4 | | A | |
| Pc | Collector Power Dissipation @ Tc=25℃ 130 | | W | |
| TJ | Junction Temperature 150 | | °C | |
| T _{stg} | Storage Temperature Range | -55~150 | °C | |

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)



Ordering Information

| Product | Package | Packaging | | |
|--------------|---------|-----------|--|--|
| 2LSA1492T4BL | TO-3PN | Tube | | |

1



2SA1492T4BL

ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | МАХ | UNIT |
|----------------------|--------------------------------------|---|------|------|------|------|
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage | I _C = -50mA ; I _B = 0 | -180 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = -5.0A; I _B = -0.5A | | | -2.0 | V |
| Ісво | Collector Cutoff Current | V _{CB} = -180V ; I _E =0 | | | -100 | μA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = -6V; I _C =0 | | | -100 | μA |
| h _{FE} | DC Current Gain | I _C = -3A ; V _{CE} = -4V | 50 | | 180 | |
| Сов | Output Capacitance | I _E = 0 ; V _{CB} = -10V;f= 1.0MHz | | 500 | | pF |
| fT | Current-Gain—Bandwidth Product | I _E = 0.5A ; V _{CE} = -12V | | 20 | | MHz |

Switching times

| t _{on} | Turn-on Time | Ic= -10A ,RL= 4 Ω , I _{B1} = -I _{B2} = -1A,Vcc= -40V | 0.6 | μs |
|------------------|--------------|---|-----|----|
| t _{stg} | Storage Time | | 0.9 | μs |
| t _f | Fall Time | | 0.2 | μs |

• h_{FE} Classifications

| 0 | Р | Y |
|-------|--------|---------|
| 50-80 | 80-130 | 130-180 |

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